

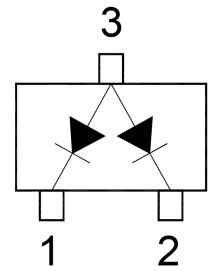
Surface Mount Schottky Barrier Diode



FEATURES:

Low forward voltage

Fast switching



SPECIFICATION:

Absolute Maximum Ratings ($T_a = 25\text{ }^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	40	V
DC Blocking Voltage	V_R	40	V
Forward Continuous Current	I_F	200	mA
Peak Forward Surge Current (at $t_p < 1\text{ s}$)	I_{FSM}	600	mA
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature Range	T_{Stg}	- 55 to + 150	$^\circ\text{C}$

Characteristics at $T_a = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Min.	Max.	Unit
Forward Voltage at $I_F = 1\text{ mA}$	V_F	-	380	mV
at $I_F = 40\text{ mA}$	V_F	-	1000	mV
Reverse Current at $V_R = 30\text{ V}$	I_R	-	200	nA
Reverse Breakdown Voltage at $I_R = 10\text{ }\mu\text{A}$	$V_{(BR)R}$	40	-	V
Reverse Recovery Time from $I_F = 10\text{ mA}$ through $I_R = 10\text{ mA}$ to $I_R = 1\text{ mA}$	t_{rr}	-	5	ns
Total Capacitance at $V_R = 0\text{ V}$, $f = 1\text{ MHz}$	C_T	-	5	pF

Art. Nr.

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